3.091 OCW Scholar

Self-Assessment Exam Crystalline Materials

Solution Key

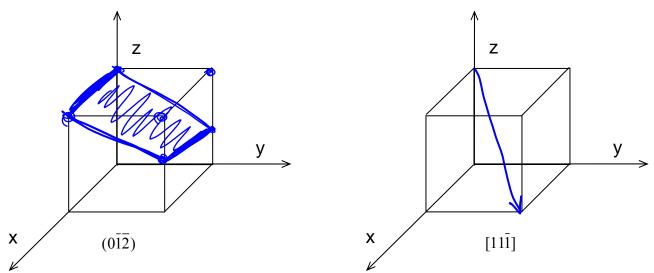
Write your answers on these pages.

State your assumptions and show calculations that support your conclusions.

RESOURCES PERMITTED: PERIODIC TABLE OF THE ELEMENTS, TABLE OF CONSTANTS, AN AID SHEET (ONE PAGE 8½" × 11"), AND A CALCULATOR.

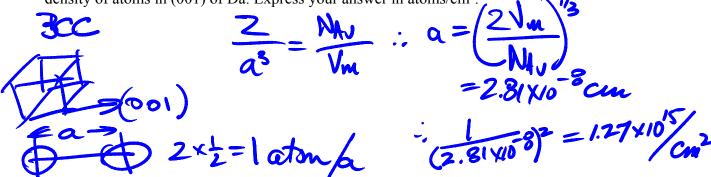
NO BOOKS OR OTHER NOTES ALLOWED.

Exam 2, Problem #1

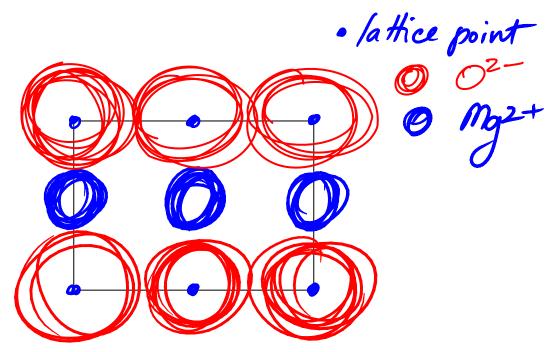


(a) For each unit cell above, draw the crystallographic feature indicated and label it clearly.

(b) Named after Salvadore Dali, dalium (Da) is BCC. Its molar volume is 6.66 cm³/mol. Calculate the density of atoms in (001) of Da. Express your answer in atoms/cm².



(c) Here is the (011) plane in a unit cell of magnesium oxide (MgO) which is FCC. Indicate the positions of all atoms lying in the plane. Represent atoms as 2-dimensional slices of space-filling spheres. The values of ionic radii are $Mg^{2+} = 0.65$ Å and $O^{2-} = 1.34$ Å. Your sketch need not be drawn to scale; however, you must convey relative values of the ionic dimensions.



Exam 2, Problem #2

(a) You discover that someone has been using your x-ray generator and has changed the target/anode. To determine the chemical identity of the new target, you go ahead and operate the x-ray generator and find the wavelength, λ , of the K_{α} peak to be 0.250 Å. What element is the target made of?

$$\frac{7}{12} = \frac{3}{4}R(Z-1)^{2} = \frac{1}{1} \implies Z = 1 + \left(\frac{4}{3R}\right)^{1/2}$$

$$\vdots Z = 1 + \left(\frac{4}{3\times 2.50\times 10^{12}}\right)^{1/2} = 23$$

$$\vdots Pu llement & V (vanadium)$$

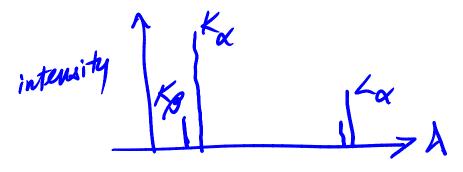
(b) Hilary Sheldon conducts an experiment with her x-ray diffractometer. A specimen of tantalum (Ta) is exposed to a beam of monochromatic x-rays of wavelength set by the K_{α} line of titanium (Ti). Calculate the value of the smallest Bragg angle, θ_{hkl} , at which Hilary can expect to observe reflections from the Ta specimen.

DATA:
$$\lambda_{K_{\alpha}}$$
 of Ti = 2.75 Å; lattice constant of Ta, $a = 3.31$ Å

 $\lambda = 2d \sin \Theta$ so smallest Θ is associated with The largest d spacing

(c) Sketch the emission spectrum (intensity *versus* wavelength) of an x-ray target that has been bombarded with *photons* instead of with electrons. Assume that the incident photons have more than enough energy to dislodge K-shell electrons in the target. On your spectrum label the features associated with K_{α} radiation, K_{β} radiation, and L_{α} radiation.

With photons, we expect to see the characteristic lines but NO Bremsstrahlung, because the interaction between photons and atoms in the target causes no deflection.



Exam 3, Problem #1

Silver bromide (AgBr) has rock salt crystal structure, i.e., FCC Bravais lattice with the ion pair, Ag⁺ and Br⁻ as basis. The dominant defect in AgBr is the Frenkel disorder.

(a) Does the Frenkel disorder in AgBr create vacancies of Ag⁺, vacancies of Br⁻, or both? Explain. The ionic radii are 0.67 Å for Ag⁺ and 1.96 Å for Br⁻.

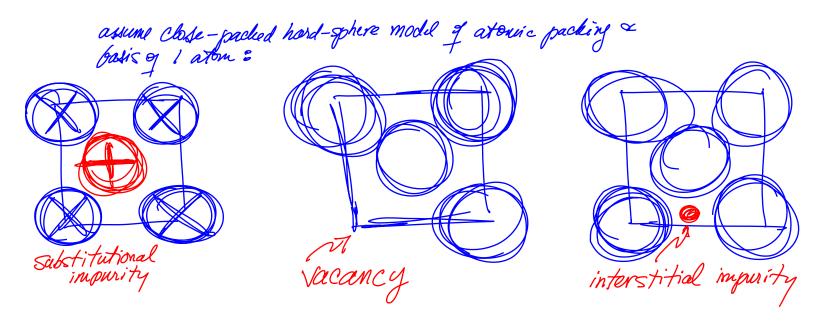
We expect the smaller ion to form interstitials and create vacancies. Here, Ag^+ is the smaller ion, so there should be Ag^+ interstitials and vacancies on the Ag^+ sublattice.

(b) Calculate the temperature at which the fraction of Frenkel defects in a crystal of AgBr exceeds 1 part per billion = 1 ppb = 10^{-9} . The enthalpy of Frenkel defect formation, $\Delta H_{\rm F}$, has a value of 1.16 eV / defect, and the entropic prefactor, A, has a value of 3.091.

 $f_{V} = A \exp \left(\frac{SH_{F}}{BT} \right) = \lim_{K \to \infty} A - \frac{SH_{F}}{BT} \Rightarrow \frac{SH_{F}}{BT} = \lim_{K \to \infty} A - \lim_{K \to \infty} V_{V}$ $00 \quad T = \int_{V} \frac{k_{B}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_{V} \frac{SH_{F}}{SH_{F}} \left(\lim_{K \to \infty} A - \lim_{K \to \infty} V_{V} \right) = \int_$

Exam 3, Problem #2

(b) On each of three separate drawings of one face of an FCC unit cell, indicate one of each of the following: (1) substitutional impurity; (2) vacancy; (3) interstitial impurity.



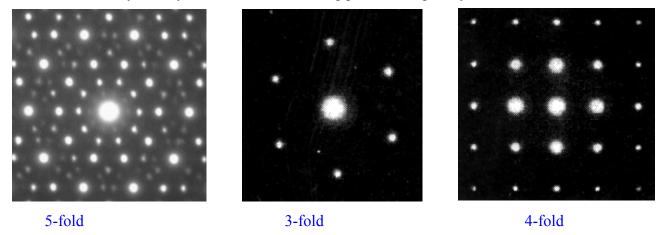
Final Exam, Problem #3

(b) Calculate the atomic packing density along [011] direction of aluminum (Al). Express your answer in units of atoms cm⁻¹.



Final Exam, Problem #4

Give the rotational symmetry of each of the following patterns. Express your answer as n-fold.



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3.091SC Introduction to Solid State Chemistry Fall 2009

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